

isc Silicon PNP Darlington Power Transistor

BDX62/A/B/C

DESCRIPTION

- Collector Current $-I_C = -8A$
- High DC Current Gain $-h_{FE} = 1000(\text{Min}) @ I_C = -3A$
- Complement to Type BDX63/A/B/C

APPLICATIONS

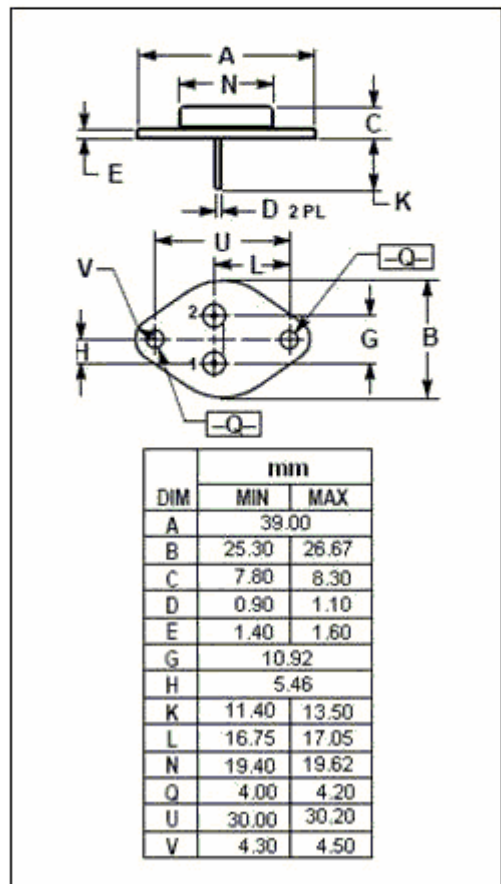
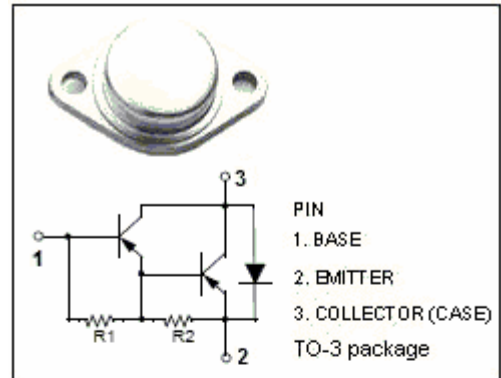
- Designed for audio output stages and general amplifier and switching applications

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CBO}	Collector-Base Voltage	BDX62	-80	V
		BDX62A	-100	
		BDX62B	-120	
		BDX62C	-140	
V_{CEO}	Collector-Emitter Voltage	BDX62	-60	V
		BDX62A	-80	
		BDX62B	-100	
		BDX62C	-120	
V_{EBO}	Emitter-Base Voltage	-5	V	
I_C	Collector Current-Continuous	-8	A	
I_{CM}	Collector Current-Peak	-12	A	
I_B	Base Current-Continuous	-0.15	A	
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	90	W	
T_J	Junction Temperature	200	$^\circ\text{C}$	
T_{stg}	Storage Temperature Range	-65~200	$^\circ\text{C}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.94	$^\circ\text{C}/\text{W}$



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ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	BDX62	$I_C = -100\text{mA}; I_B = 0$	-60			V	
		BDX62A		-80				
		BDX62B		-100				
		BDX62C		-120				
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -3\text{A}; I_B = -12\text{mA}$			-2	V		
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -3\text{A}; V_{CE} = -3\text{V}$			-2.5	V		
I_{CEO}	Collector Cutoff Current	$V_{CE} = \frac{1}{2}V_{CE0}; I_B = 0$			-0.2	mA		
I_{CBO}	Collector Cutoff Current	$V_{CB} = V_{CB0max}; I_E = 0$			-0.2	mA		
I_{CBO}	Collector Cutoff Current	BDX62				-2	mA	
		BDX62A						$V_{CB} = -40\text{V}; I_E = 0; T_J = 200^\circ\text{C}$
		BDX62B						$V_{CB} = -50\text{V}; I_E = 0; T_J = 200^\circ\text{C}$
		BDX62C						$V_{CB} = -60\text{V}; I_E = 0; T_J = 200^\circ\text{C}$
I_{EBO}	Emitter Cutoff Current	$V_{EB} = -5\text{V}; I_C = 0$			-5	mA		
h_{FE-1}	DC Current Gain	$I_C = -0.5\text{A}; V_{CE} = -3\text{V}$		1500				
h_{FE-2}	DC Current Gain	$I_C = -3\text{A}; V_{CE} = -3\text{V}$	1000					
h_{FE-3}	DC Current Gain	$I_C = -8\text{A}; V_{CE} = -3\text{V}$		750				
C_{OB}	Output Capacitance	$I_E = 0; V_{CB} = -10\text{V}; f_{test} = 1\text{MHz}$		100		pF		

Switching times

t_{on}	Turn-on Time	$I_C = -3\text{A}; I_{B1} = -I_{B2} = -12\text{mA}$		0.5		μs
t_{off}	Turn-off Time			2.5		μs